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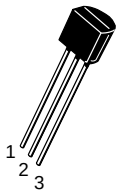
Jameco Part Number 254781

ON Semiconductor™

Amplifier Transistors
NPN Silicon

BC546
BC546B
BC547A
BC547B
BC547C
BC548B
BC548C



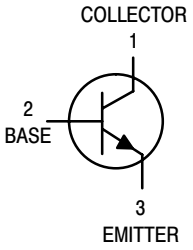
CASE 29–04, STYLE 17
TO–92 (TO–226AA)

MAXIMUM RATINGS

Rating	Symbol	BC546	BC547	BC548	Unit
Collector–Emitter Voltage	V_{CEO}	65	45	30	Vdc
Collector–Base Voltage	V_{CBO}	80	50	30	Vdc
Emitter–Base Voltage	V_{EBO}	6.0			Vdc
Collector Current — Continuous	I_C	100			mAdc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	625 5.0			mW mW/°C
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	1.5 12			Watt mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150			°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage (I_C = 1.0 mA, I_B = 0)	BC546 BC547 BC548	$V_{(BR)CEO}$	65 45 30	— — —	— — —	V
Collector–Base Breakdown Voltage (I_C = 100 μAdc)	BC546 BC547 BC548	$V_{(BR)CBO}$	80 50 30	— — —	— — —	V
Emitter–Base Breakdown Voltage (I_E = 10 μA, I_C = 0)	BC546 BC547 BC548	$V_{(BR)EBO}$	6.0 6.0 6.0	— — —	— — —	V
Collector Cutoff Current		I_{CES}				
(V_{CE} = 70 V, V_{BE} = 0)	BC546		—	0.2	15	nA
(V_{CE} = 50 V, V_{BE} = 0)	BC547		—	0.2	15	
(V_{CE} = 35 V, V_{BE} = 0)	BC548		—	0.2	15	
(V_{CE} = 30 V, T_A = 125°C)	BC546/547/548		—	—	4.0	μA

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS						
DC Current Gain		h_{FE}				—
(I_C = 10 μA, V_{CE} = 5.0 V)	BC547A		—	90	—	
	BC546B/547B/548B		—	150	—	
	BC548C		—	270	—	
(I_C = 2.0 mA, V_{CE} = 5.0 V)	BC546		110	—	450	
	BC547		110	—	800	
	BC548		110	—	800	
	BC547A		110	180	220	
	BC546B/547B/548B		200	290	450	
	BC547C/BC548C		420	520	800	
(I_C = 100 mA, V_{CE} = 5.0 V)	BC547A/548A		—	120	—	
	BC546B/547B/548B		—	180	—	
	BC548C		—	300	—	
Collector–Emitter Saturation Voltage		$V_{CE(sat)}$				V
(I_C = 10 mA, I_B = 0.5 mA)			—	0.09	0.25	
(I_C = 100 mA, I_B = 5.0 mA)			—	0.2	0.6	
(I_C = 10 mA, I_B = See Note 1)			—	0.3	0.6	
Base–Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA)		$V_{BE(sat)}$	—	0.7	—	V
Base–Emitter On Voltage		$V_{BE(on)}$				V
(I_C = 2.0 mA, V_{CE} = 5.0 V)			0.55	—	0.7	
(I_C = 10 mA, V_{CE} = 5.0 V)			—	—	0.77	
SMALL–SIGNAL CHARACTERISTICS						
Current–Gain — Bandwidth Product		f_T				MHz
(I_C = 10 mA, V_{CE} = 5.0 V, f = 100 MHz)	BC546		150	300	—	
	BC547		150	300	—	
	BC548		150	300	—	
Output Capacitance (V_{CB} = 10 V, I_C = 0, f = 1.0 MHz)		C_{obo}	—	1.7	4.5	pF
Input Capacitance (V_{EB} = 0.5 V, I_C = 0, f = 1.0 MHz)		C_{ibo}	—	10	—	pF
Small–Signal Current Gain		h_{fe}				—
(I_C = 2.0 mA, V_{CE} = 5.0 V, f = 1.0 kHz)	BC546		125	—	500	
	BC547/548		125	—	900	
	BC547A		125	220	260	
	BC546B/547B/548B		240	330	500	
	BC547C/548C		450	600	900	
Noise Figure		NF				dB
(I_C = 0.2 mA, V_{CE} = 5.0 V, R_S = 2 kΩ,	BC546		—	2.0	10	
f = 1.0 kHz, Δf = 200 Hz)	BC547		—	2.0	10	
	BC548		—	2.0	10	

Note 1: I_B is value for which I_C = 11 mA at V_{CE} = 1.0 V.

BC547/BC548

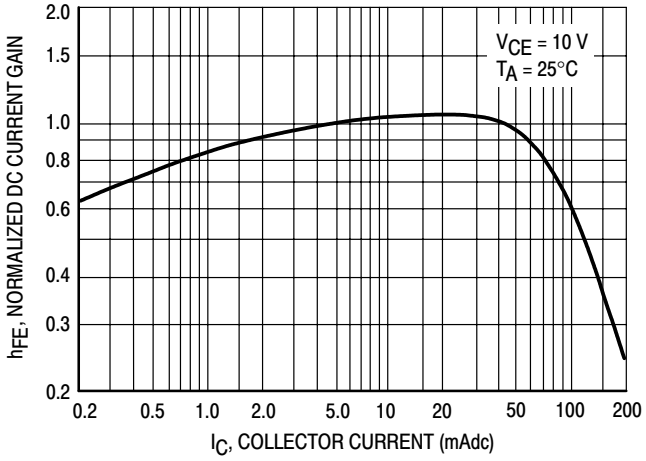


Figure 1. Normalized DC Current Gain

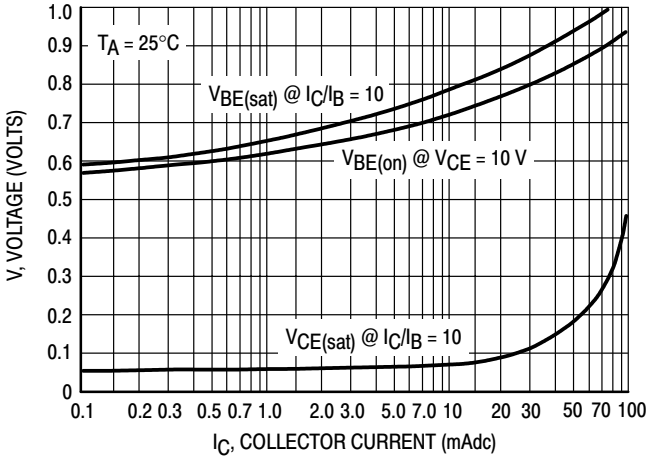


Figure 2. "Saturation" and "On" Voltages

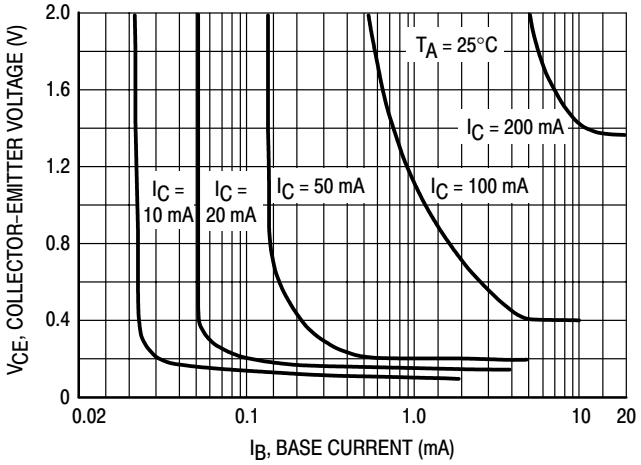


Figure 3. Collector Saturation Region

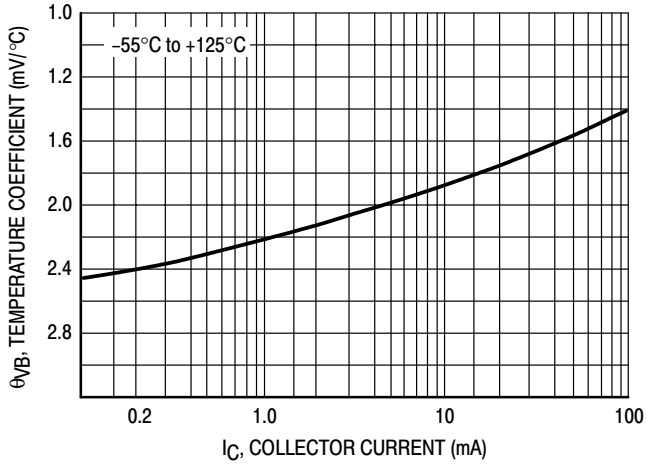


Figure 4. Base–Emitter Temperature Coefficient

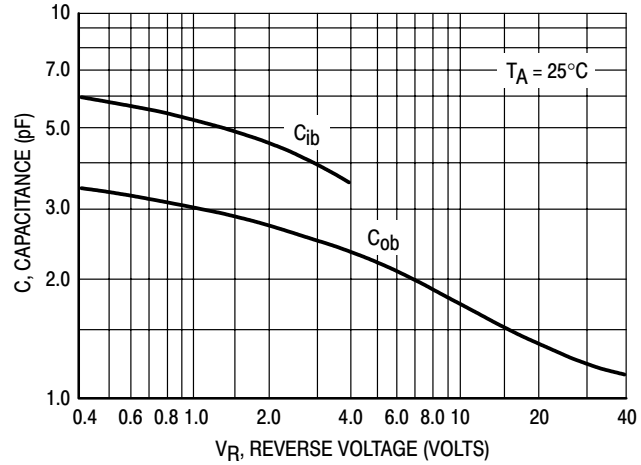


Figure 5. Capacitances

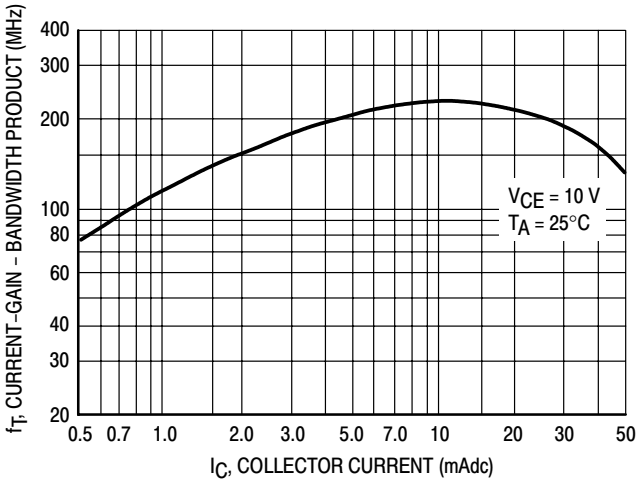


Figure 6. Current–Gain – Bandwidth Product

BC546

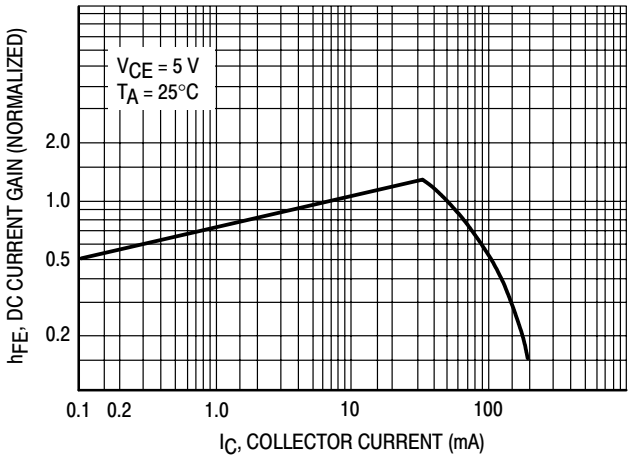


Figure 7. DC Current Gain

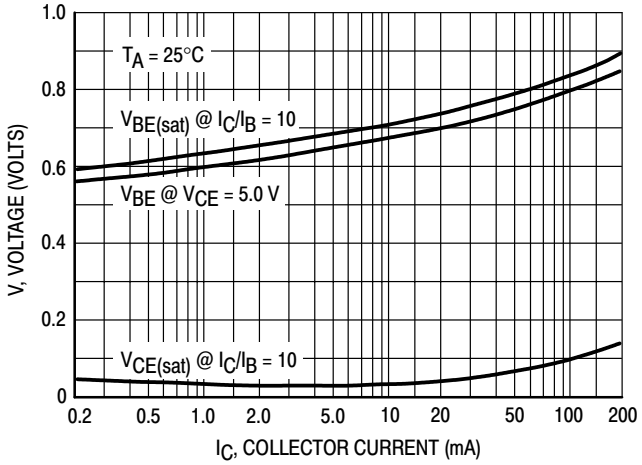


Figure 8. “On” Voltage

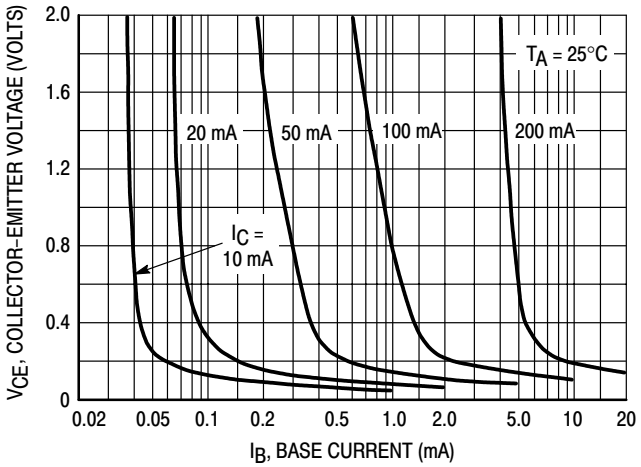


Figure 9. Collector Saturation Region

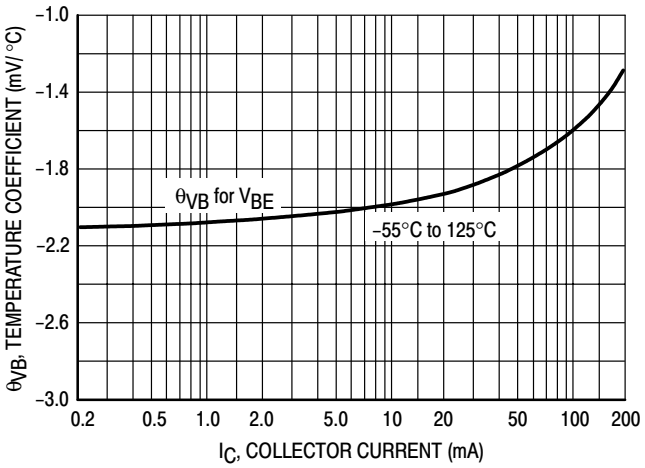


Figure 10. Base–Emitter Temperature Coefficient

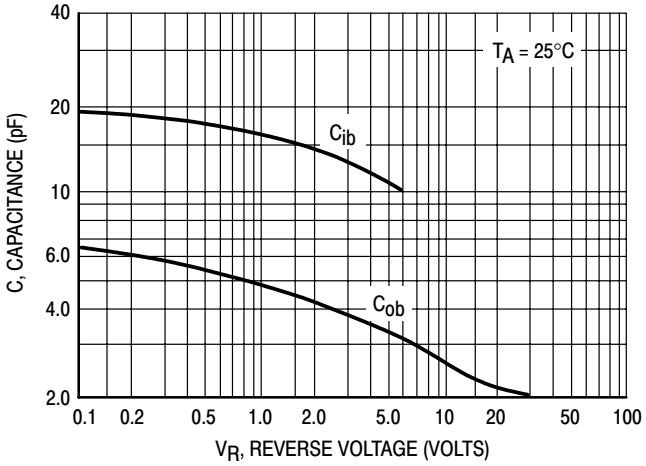


Figure 11. Capacitance

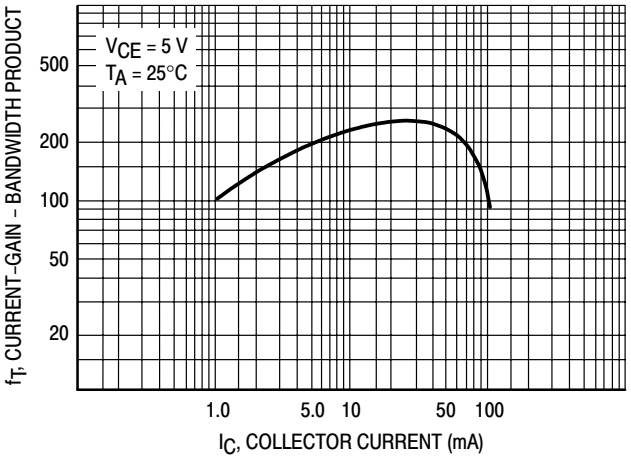
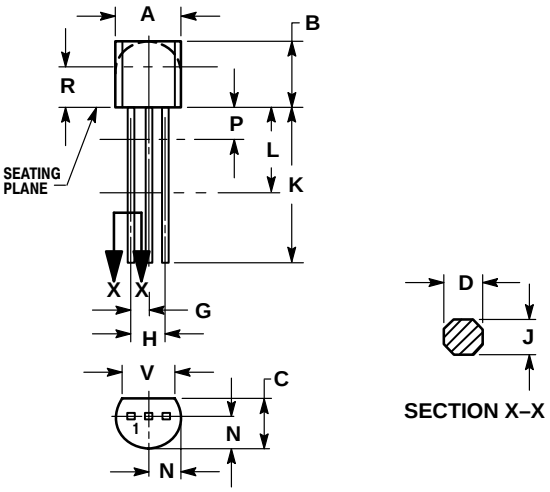


Figure 12. Current–Gain – Bandwidth Product

PACKAGE DIMENSIONS

TO–92 (TO–226)
CASE 29–11
ISSUE AL



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

Notes

Notes

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